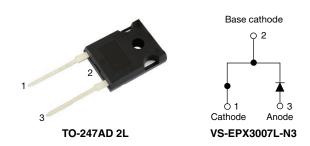
### Vishay Semiconductors

www.vishay.com

Hyperfast Rectifier, 30 A FRED Pt<sup>®</sup>



### LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS									
I <sub>F(AV)</sub>	30 A								
V <sub>R</sub>	650 V								
V <sub>F</sub> at I <sub>F</sub>	1.6 V								
t <sub>rr</sub> typ.	27 ns								
T <sub>J</sub> max.	175 °C								
Package	TO-247AD 2L								
Circuit configuration	Single								

### FEATURES

- Low forward voltage drop
- Hyperfast soft recovery time
- 175 °C operating junction temperature
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **DESCRIPTION / APPLICATIONS**

Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC Boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

### **MECHANICAL DATA**

Case: TO-247AD 2L

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS						
Repetitive peak reverse voltage	V <sub>RRM</sub>		650	V						
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 111 °C	30	Α						
Non-repetitive peak surge current	I <sub>FSM</sub>	$T_C = 25 \text{ °C}, t_p = 8.3 \text{ ms}, \text{ half sine wave}$	170	A						
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C						

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Breakdown voltage, blocking voltage	$V_{BR}, V_{R}$	I <sub>R</sub> = 100 μA	650	-	-				
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 30 A	-	2.1	2.5	V			
		I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C	-	1.6	1.7				
		$V_{R} = V_{R}$ rated	-	0.02	30				
Reverse leakage current	I <sub>R</sub>	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	300	μΑ			
Junction capacitance	CT	V <sub>R</sub> = 650 V	-	22	-	pF			
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nH			

Revision: 21-Jan-2021

Document Number: 96449

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

1

RoHS COMPLIANT HALOGEN



www.vishay.com

## **Vishay Semiconductors**

<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25 \text{ °C}$ unless otherwise specified)									
PARAMETER	SYMBOL	TEST CON	DITIONS	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}$	Vµs, V <sub>R</sub> = 30 V	-	35	-			
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	27	-	ns		
		T <sub>J</sub> = 125 °C		-	88	-			
Doold recovery ourrept	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C	$I_{\rm F} = 30  {\rm A}$	-	15	-	А		
Peak recovery current		T <sub>J</sub> = 125 °C	dl <sub>F</sub> /dt = 1000 A/µs V <sub>B</sub> = 400 V	-	24	-	A		
	0	T <sub>J</sub> = 25 °C		-	330	-			
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	1350	-	nC		

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C				
Thermal resistance, junction to case	R <sub>thJC</sub>		-	0.7	1.1	°C/W				
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.5	-					
Weight			-	5.5	-	g				
Weight			-	0.2	-	oz.				
Mounting torque			1.2 (10)	-	2.4 (20)	kgf · cm (lbf · in)				
Marking device		Case style TO-247 2L		EPX3	8007L					

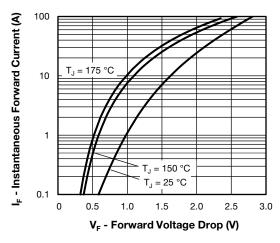


Fig. 1 - Typical Forward Voltage Drop Characteristics

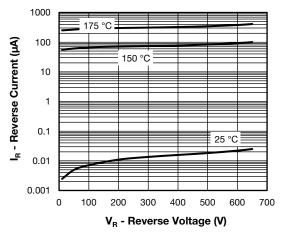


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

# **VS-EPX3007L-N3**

### **Vishay Semiconductors**

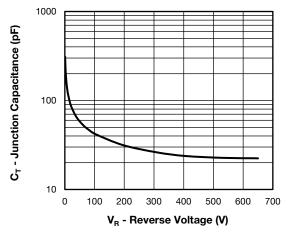


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

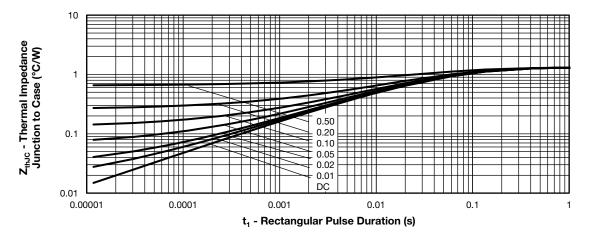
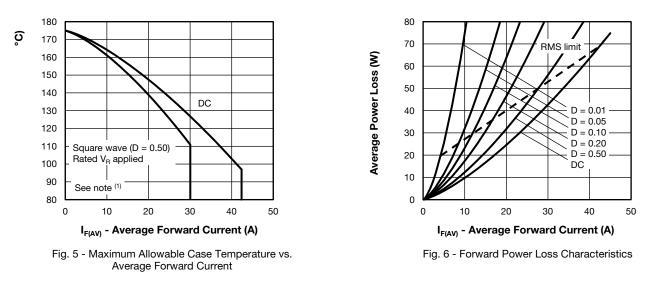


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics



SHAY

www.vishay.com

3

Document Number: 96449

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

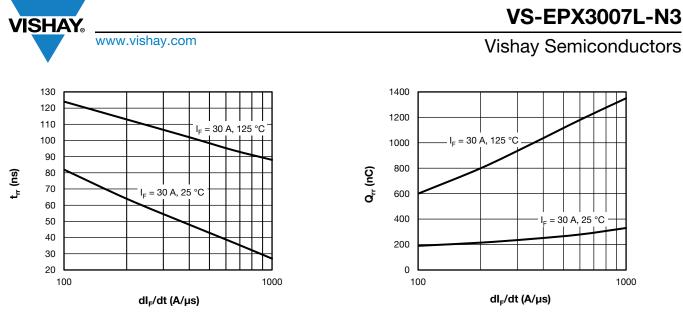


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

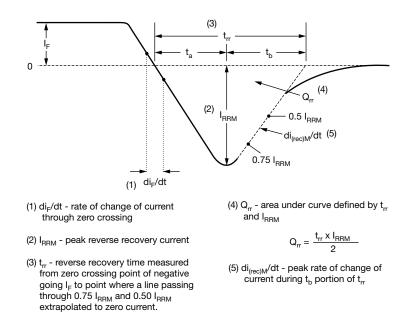


Fig. 9 - Reverse Recovery Waveform and Definitions

## Vishay Semiconductors



### **ORDERING INFORMATION TABLE**

Device code	vs-	Е	Р	x	30	07	L	-N3
		_	-	~				
		2	3	4	5	6	7	8
	1 -	- Visl	nay Sem	niconduc	ctors pro	oduct		
	2 -	E =	single c	liode				
	3 -	- P=	TO-247	,				
	4 -	- X =	hyperfa	st recov	ery time	Э		
	5 -	Cur	rent coc	le (30 =	30 A)			
	6 -	Volt	age coo	de (07 =	650 V)			
	7 -	- L=	long lea	d				
	8 -			ntal digit en-free,		complia	nt and t	totally le
		110	nalog	,011 1100,	1.0110	complic	and and	io cany io

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-EPX3007L-N3	25	500	Antistatic plastic tube						

LINKS TO RELATED DOCUMENTS							
Dimensions www.vishay.com/doc?95536							
Part marking information	www.vishay.com/doc?95648						



**Vishay Semiconductors** 

**TO-247AD 2L** 

### **DIMENSIONS** in millimeters and inches



Section C - C, D - D

(b, b2)

(4)

View	<u>/ B</u>

SYMBOL	DL MILLIMETERS INCHES NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES				
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	STMDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209		E	15.29	15.87	0.602	0.625	3
A1	2.21	2.59	0.087	0.102		E1	13.46	-	0.53	-	
A2	1.50	2.49	0.059	0.098		е	5.46	BSC	0.215	5 BSC	
b	0.99	1.40	0.039	0.055		ØК	0.2	254	0.0	010	
b1	0.99	1.35	0.039	0.053		L	19.81	20.32	0.780	0.800	
b2	1.65	2.39	0.065	0.094		L1	3.71	4.29	0.146	0.169	
b3	1.65	2.34	0.065	0.092		ØР	3.56	3.66	0.14	0.144	
С	0.38	0.89	0.015	0.035		Ø P1	-	6.98	-	0.275	
c1	0.38	0.84	0.015	0.033		Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3	R	4.52	5.49	0.178	0.216	
D1	13.08	-	0.515	-	4	S	5.51	BSC	0.217	' BSC	
D2	0.51	1.35	0.020	0.053			•		•		•

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

(5) Lead finish uncontrolled in L1

<sup>(6)</sup> Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

Revision: 28-May-2018 Document Number: 95536 1 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000



Vishay

# Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2024 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED

Revision: 01-Jul-2024